# Therm al rectifying e ect in two dimensional anharm onic lattices

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We study them al rectifying e ect in two dimensional (2D) systems consisting of the Frenkel Kontorva (FK) lattice and the Ferm iPasta-Ulam (FPU) lattice. It is found that the rectifying e ect is related to the asym metrical interface them al resistance. The rectifying e ciency is typically about two orders of magnitude which is large enough to be observed in experiment. The dependence of rectifying e ciency on the temperature and temperature gradient is studied. The underlying mechanism is found to be the match and mism atch of the spectra of lattice vibration in two parts.

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#### I. IN TRODUCTION

conduction low Heat in dim ensystem s attracted increasing sional has attention1,2,3,4,5,6,7,8,9,10,11,12,13,14,15,16,17,18,19,20,21,22,23 in recent years. After two decades analytic and numerical studies in 1D model, much progress has been achieved. On the one hand, the study has enriched our understanding about the underlying physical mechanism. On the other hand, the study has made it possible to seek the practical application of heat control and management. Indeed, in 2002, Terraneo et  $al^{24}$ proposed a thermal device which can rectify the heat current through it when reversing the temperature gradient. The model proposed by Terraneo et al is a 1D anharm onic lattice consisting of three segments with the Morse on-site potential of dierent parameters. As the rst attempt of controlling heat current, the ratio of the therm al current changes is less than two. More recently, Liet al.<sup>25</sup> construct a therm aldiode model in which two Frenkel-Kontoroval (FK) chains with di erent nonlinear strengths are connected by a harm onic spring. The most successful improvement of the model by Li et al<sup>25</sup> lies in three facts: First, the con guration is more simple, it consists of only two di erent segments; Second, the ratio of heat current from two dierent directions is increased drastically about 100 times; Third, the underlying mechanism of thermal rectifying e ect is explained by illustrating the phonon bands of the particles in dierent segments. Following Liet al's work, we further improve the rectifying e ciency from 100 to 2000 by substituting the weak FK chain with a Ferm i-Pasta-Ulam (FPU) chain<sup>26</sup>. In addition, we nd that the rectifying e ect (asymmetric heat ow) is closely related to asymmetric interface therm al resistance (also called K apitza resistance). M oreover, a specic relationship between the ratio of heat current

and the overlap of the phonon spectra is demonstrated numerically. The rectifying e ect can also be achieved by modulating the periodicity of the on-site potential of the FK lattice<sup>27</sup>.

The above works demonstrate the possibility of controlling heat current by changing structures/param eters of anham onic lattices. These might nd potential application in energy saving material. However, almost all works so far are focused on 1D system of nite size. Obviously, much progress has been achieved, but the nal purpose is to put these ideas to application. It is thus a nature step forward to seek e ective therm al devices to control heat current in higher dimension. The open questions are: whether the heat controlm echanism in 1D is still valid for the high dimension (s) and whether the extra dimension (s) reduces the rectifying e ciency? The answerm ight not be trivial, as in higher dimension the lattice vibration includes not only the longitudinal one but also the transverse ones. The longitudinal modes will couple to the transverse modes<sup>28</sup>, which might a ect the rectifying e ciency.

In this paper, we concentrate our study on a 2D rectierm odel. W e will dem onstrate with num erical evidence that a 2D recti er can be built up and it works in a very wide tem perature range. The 2D therm al recti er show s sim ilar behaviors with 1D therm al recti er under sim ilar param eters regim es.

The paper is organized as the follows. In Section II, we describe our model and numerical method used for the computer simulation. In Section III, we demonstrate and discuss the dependence of the thermal rectifying e ciency on the temperature and the temperature gradient. Section IV is devoted to the interface thermal resistance which is the key point to understand the thermal rectifying e ect. In Section V, we give physical understanding of the rectifying e ect in terms of the lattice vibration spectra (also called phonon band.) We conclude the pa-



FIG.1: (Color Online) Conguration of a two dimensional (2D) them al recti er from the Frenkel Kotoroval and the Ferm iPasta-U lam lattices. The left part is a 2D FK lattice and the right one is a 2D Ferm iPasta-U lam lattice. The two parts are connected by harm onic springs with constant  $k_{\rm int}$ . The left and the right ends are put into contact with heat baths of tem perature  $T_{\rm L}$  and  $T_{\rm R}$ , respectively.

per by conclusions and discussions in Sec. V I.

#### II. MODEL AND METHODOLOGY

In our previous work<sup>26</sup>, we construct a 1D therm al diode model by connecting a FK lattice to a FPU lattice with a weak harm onic spring. We denote it as 1D-FK-FPU model. This model displays a very good rectifying e ect. In this paper, we extend the 1D -FK -FPU therm al recti er m odel to two dim ensional one. W e denote it as a 2D-FK-FPU model. The con guration of the 2D-FK-FPU model is illustrated in Fig1. The left part is a plane of harm onic oscillators on a substrate whose interaction is represented by a sinusoidal on-site potential. Here we plot the contour line of the 2D sinusoidal potential. For simplicity, we put one particle in each valley. The right part is an array of an-harm on ic oscillators represented by the FPU model. The two parts are connected by weak harm onic springs. The Ham iltonian of the system can be written as:

$$H = H_{FK} + H_{FPU} + H_{int}; \qquad (1)$$

where  $H_{FK}$ ,  $H_{FPU}$ ,  $H_{int}$  is the Ham iltonian of the left part, the right part and the interface section, respectively. They are represented in (2), (3), (4), respectively.

$$H_{FK} = \sum_{i=1}^{N_{FK}} (\frac{p_{i,j}^{2}}{2} + k_{FK} V_{H} (j_{i,j,i-1,j} j l_{0})$$
(2)

+ 
$$K_{FK} \vee_{H} ((\mathcal{F}_{i;j;i;j 1} \cup 0)) + \cup_{FK} (X_{i;j}; Y_{i;j}))$$

$$H_{FPU} = \sum_{i=N_{FK}+1}^{X \times X^{Y}} (\frac{p_{i,j}^{2}}{2} + k_{FPU} V_{FPU} (j_{i,j;i-1;j} j l_{0}) + k_{FPU} V_{FPU} (j_{i,j;i,j-1} j l_{0}))$$
(3)

$$H_{int} = \begin{array}{c} X^{Y} \\ H_{int} = & k_{int} V_{H} (j_{N_{FK}}; j_{N_{FK}} + 1; j j l_{0}) \\ j = 1 \end{array}$$
(4)

where  $\mathbf{r}_{i;j;k;l} = \mathbf{q}_{i;j}$   $\mathbf{q}_{k;l}$  is the relative displacement between particles, labelled as (i; j) and (k;l).  $V_H(\mathbf{x}) = \frac{1}{2}\mathbf{x}^2$ ,  $V_{F\,P\,U}(\mathbf{x}) = \frac{1}{2}\mathbf{x}^2 + \frac{1}{4}\mathbf{x}^4$ ,  $U_{F\,K}(\mathbf{x};\mathbf{y}) = \frac{A}{(2-)^2}\cos(\frac{2}{l_0}\mathbf{x})\cos(\frac{2}{l_0}\mathbf{y})$ .

The mass of the particles is uniform by 1.  $l_0$  is distance between nearest neighbors in equilibrium. The particle at the ith column and the jth row is labelled as (i; j). The coordinate and m om entum of this particle is  $q_{i;j} = (x_{i;j}; y_{i;j})$  and  $p_{i;j} = (p_{x_{i;j}}; p_{y_{i;j}})$ . In order to establish a tem perature gradient, the two ends of the planes are put into contact with two Nose-Hooverheat bathes<sup>29</sup> with tem perature  $T_L$  and  $T_R$  for the left end and the right end, respectively. Particles for  $i = 1; j = 1; 2; 3::: \mathbb{N}_Y$ are coupled with heat bath of tem perature  $T_L$  and particles for  $i = N_X$ ;  $j = 1; 2; 3::: N_Y$  are coupled with heat bath of tem perature  ${\rm T}_{\rm R}$  . We checked in 1D case that the result does not depend on the particular heat bath realization. Fixed boundary condition is used along tem perature gradient direction, denoted as X direction in this paper, namely,  $q_{0;j} = (0; j), q_{N_x + 1;j} = (N_x + 1; j)$ . Periodic boundary condition is applied in the Y direction, namely,  $q_{i;1} = q_{i;N_Y+1}$  (see Fig. 1). Under these boundary conditions, the system can be considered as a tube. The total num ber of particles is N  $_{\rm X}$ N<sub>y</sub>.Allresults given in this paper are obtained by averaging over  $10^8$  (N > 2) steps after a su cient long transient time Ν when a non-equilibrium stationary state is set up. The equations of motion of the particles are:

$$\mathbf{g}_{1;j} = \mathbf{p}_{i,j};$$

$$\mathbf{g}_{1;j} = \begin{cases} 8 & \frac{2H}{2} \mathbf{q}_{i,j} & (i = 2; N_X \quad 1); \\ \vdots & \frac{2H}{2} \mathbf{q}_{i,j} & \mathbf{q}_{i,j} \mathbf{p}_{i,j} & (i = 1; N_X); \end{cases}$$
(5)

and the auxiliary variables  $_{i;j}$  are described by the equations:

p

$$\underline{\tau}_{;j} = \frac{1}{Q} \left( \frac{p_{i;j}^2}{2k_B T} \right);$$
(6)

here, T is the tem perature of the heat bath ( $T_{\rm L}$  or  $T_{\rm R}$ ), and Q is the parameter of coupling between the therm al bath and the system . In this study, we set Q = 1 so that the response time of the therm ostats,  $p\frac{1}{Q}$ , is of the same order of the original time scale of the lattice. Our purpose is to study rectifying e ect in two dimension and the dependence of the rectifying e ciency on the system tem perature and the tem perature gradient, so we don't attempt to search the optimum setting of parameters. We choose the system parameters same as in 1D FK – FPU m odel which has been tested as good one in 1D case, that is  $k_{\rm FK} = 1$ , A = 5,  $l_0 = 1$ ,  $k_{\rm FPU} = 0.2$  and

$$T_{L} = T_{0} (1 + );$$
  
 $T_{R} = T_{0} (1 );$ 
(7)

where 0.8 0.8 in our simulations. So we can simply denote  $T_0$  as the tem perature added on the system and 2 = (T $_{\rm R}$  $T_{\rm L}$ )=T $_0$  as the norm alized tem perature di erence of the system .

The temperature used in our numerical simulation is dimensionless. It is connected with the true temperature  $T_r$  through the following relation<sup>9</sup>,  $T_r = \frac{m + \frac{1}{0}b^2}{k_B}T$ ; where m is the mass of the particle and b is the period of external potential.  $!_0$  is the vibration frequency.  $k_B$  is the Boltzman constant. For the typical values of atom s, we have  $T_r$  ( $10^2 + 10^3$ )<sup>9</sup>, which means that the room temperature corresponds to the dimensionless temperature T (0:1 1).

The local tem perature is de ned as

$$T_{i;j} = \frac{1}{2} m h v_{i;j}^2 i;$$
 (8)

where h:::i stands for a tem poralaverage. The local heat current  $J_{i;j}$  is dened as the energy transfer per unit time from the particle labelled as (i; j) to the nearest particles along X direction.

$$J_{i;j} = \mathbf{v}_{i;j} \ \mathbf{F}_{i;j}$$
  
=  $k \mathbf{v}_{i;j} \ \frac{\varrho \ (V \ (\mathbf{j} \mathbf{e}_{i+1;j;i;j} \ j \ l_0) + V \ (\mathbf{j} \mathbf{e}_{i;j;i-1;j} \ j \ l_0))}{\varrho \mathbf{q}_{i;j}};$   
(9)

where  $k = k_{FK}$ ;  $k_{FPU}$  or  $k_{int}$ , depending on the site along X direction. For a 2D -lattice, we treat only heat current owing along the X -direction. We denote the current from the particles in ith section to the next section in the X -direction simply as  $J_i (J_i = \prod_{j=1}^{N_Y} J_{ij})$ . The total current of the system is averaged over all sections,

$$J = \frac{1}{N_{X}} h_{i=1}^{X^{\times}} J_{i}i:$$
(10)

In our simulations, the uctuations of temporal heat current through each section are all less than ve percents. We use  $jJ_+=J_-$  j as a rectifying e ciency, to describe quantitatively the rectifying perform ance of the system  $.J_+$  is the current when is positive (heat ow s from the FK part to the FPU part) and J is the current when is negative (heat ow s from the FPU part to the FK part).

The model we used is a simple extension from one dimension to two dimension, however the results in Fig2 show that it truly demonstrates good rectifying e ect on heat current. In Fig 2, we can see the visible di erence between  $J_+$  and  $J_-$  in very wide temperature range. The di erence varies from few times to several hundreds times.



FIG.2: (ColorOnline) Heat current of the system with N  $_{\rm Y}$  = 4 and N  $_{\rm X}$  = 10 versus T\_0.j = 0.5

### III. DEPENDENCE OF RECTIFYING EFFECT ON TEMPERATURE AND TEMPERATURE DIFFERENCE

In this section, we study the dependence of the system perform ance on the tem perature change. Fig 3 shows the rectifying e ciency  $jJ_{+}=J_{-}j$  versus  $T_{0}$ . In Fig3(a), we can see that there exists an optimum performance (OP) of the rectifying e ect when changing tem perature T<sub>0</sub>. We can de ne the tem perature for the optim um perform ance as  $T_{OP}$ . In Fig3b, Fig3c and Fig3d we show the dependence of the ratio  $jJ_{+} = J_{-}j$  on tem perature under di erent conditions. W e found that  $T_{OP}$  depends on the system settings along Y direction. In Fig3b, the num ber of particles along Y direction varies from 4 to 8 and 16 while other settings are kept unchanged. W e can see clearly that  $T_{OP}$  shifts to lower temperature when increasing N  $_{\rm Y}$  . The value of T $_{\rm OP}$  is 0.04, 0.037, 0.0325 for N<sub>Y</sub> = 4, 8 and 16, respectively.  $T_{OP}$  keeps the same value when we change N  $_{\rm X}$  . This is shown in Fig3c. In Fig3d, we change the periodic boundary condition in Y direction to free boundary condition.  $T_{OP}$  and the optimum perform ance change drastically.  $T_{OP}$  changes from 0.037 to 0.025 and the ratio increases alm ost 100% .

Q uantity W<sub>T</sub> in the gures is a parameter de ned as the width of the elective temperature range T<sub>e</sub> over the half value of OP, while  $\# = W_T = T_{OP}$  is de ned as the quality factor. T<sub>e</sub>, W<sub>T</sub>, and  $\# = W_T = T_{OP}$  are useful parameters to estimate the temperature range in which the system has a good rectifying elect. In our investigation, T<sub>e</sub> broadens from the center [0.03-0.46] to high temperature region or low temperature region. The typical value of W<sub>T</sub> under dilerent settings is around 0.018-0.023. # is always larger than 0.5. The results suggest that the system is elective in very wide temperature range.

In Fig4, we show the heat current versus the (norm alized) tem perature di erence, , for three di erent T $_0$ . Full sym bols represent  $J_+$  and empty ones  $j J_- j.$  W e can



FIG.3: (ColorOnline) The rectifying e ciency, jJ + = J j versus  $T_0$  at di erent conditions. (a) The system with  $N_Y = 4$ ,  $N_X = 10$ , and jj = 0.5.  $T_{OP} = 0.04$ . (b) Comparison for three dierent N  $_{\rm Y}$  with N  $_{\rm X}$  = 40. T $_{\rm OP}$  = 0:04, W  $_{\rm T}$  = 0:022 and # = 0:55 for the case of N  $_{\rm Y}$  = 4. W hen N  $_{\rm Y}$  = 8, T  $_{\rm O\,P}$  = 0:037, W  $_{\rm T}$  = 0:022 and # = 0:59. W hen  $N_{Y} = 16, T_{OP} = 0.0325, W_{T} = 0.018$  and # = 0.55.(c)Comparison for three di erent N  $_X$  with N  $_Y$  = 8. They have the same T\_OP = 0:037. W hen N  $_{\rm X}$  = 10, W  $_{\rm T}$  = 0:023 and # = 0:62. W hen N<sub>X</sub> = 20, W<sub>T</sub> = 0:020 and # = 0:54. W hen N<sub>X</sub> = 40, W<sub>T</sub> = 0:022 and # = 0:59. (d) C om parison for di erent boundary conditions along Y direction with  $N_{Y} = 8$ ;  $N_{X} = 20$ . Free boundary: The optimum perform ance (OP)OP = 298:5,  $T_{OP}$  = 0:025,  $W_T$  = 0:014, # = 0.56; Periodic boundary: OP = 191.5,  $T_{OP} = 0.037$ ,  $W_T = 0:022, \# = 0:59.$ 

see that  $J_+$  increases with monotonically and it always larger than  $jJ_{j}$  while J changes with in di erent ways. One can nd that there are three regions for  $jJ_{j}$ . In the nst region, jj < 0.1, the increase of leads to the increase of the heat current. However, in the second region, 0.1 < jj < 0.6, the increase of j j does not induce the increase of  $jJ_{j}$  instead it results in a decrease of  $jJ_{j}$ . In the third region, > 0.6,  $jJ_{j}$  j is almost a constant independent of j j. In this region, the  $jJ_{j}$  is so sm all that the system can be approximately considered as an insulator. The ratio  $jJ_{+}=J_{j}$  j becomes larger and larger when j j increases. That indicates that rectifying



FIG.4: (ColorOnline) Heat current of the system with N $_{\rm Y}$  = 8;N $_{\rm X}$  = 20 versus temperature di erence at three di erent T<sub>0</sub>. Note that jJ jdecreases as jjincreases in the interval 0:1 < jj < 0:6, this is the so-called "negative di erential therm al resistance", see context for more explanation.



FIG.5: (Color Online) The ratio of heat current,  $jJ_+ =J_- j$  versus half norm alized tem perature di erence j jat tem perature  $T_0 = 0.037; 0.045; 0.05$ . The dotted line has a slope of 9.5.

e ect increases with increasing tem perature di erence.

The strange behavior of jJ j observed in the second region, namely, the larger the temperature di erence the smaller the heat current, is called negative di erential therm al resistance. As we will demonstrate later that this is a typical phenomenon in nonlinear lattices. It can be understood from the match and m ism atch of the vibrational spectra of the interface particles.

Fig5 shows  $jJ_+ = J$  j versus jj. It is found that  $jJ_+ = J$  j increases with j j in an exponential way in the regime in which j j is smaller than 2. Approximately,

$$jJ_{+} = J j / \exp(c j j) + ;$$
 (11)



FIG. 6: (Color Online)  $T = T_0$  versus lattice site for  $T_0 = 0.05$ , 0.07, and 0.09. The solid symbols are for the cases of = 0.5 and the empty symbols are for the cases of = 0.5. N  $_Y = 8$ ; N  $_X = 20$ .

here c is about 9.5 under the particular parameter setting N<sub>Y</sub> = 8 and N<sub>X</sub> = 20 with periodic boundary condition along Y direction. W hen we change N<sub>Y</sub>, N<sub>X</sub> or boundary condition along Y direction, c changes slightly, but it is always around 10. The variation of  $j_{\rm C}$  10 j is smaller than 0.5 in our investigation. is related with T<sub>0</sub> and

## IV. IN TERFACE THERM AL RESISTANCE (ITR) - KAP IT ZA RESISTANCE

Therm al resistance between two di erent m aterials or between twin or twist boundaries of the same m aterial has been extensively studied both experimentally and theoretically<sup>30,31,32,33</sup>. In fact, the existence of a therm alboundary resistance between a solid and super uid helium was rst detected by K apitza<sup>33</sup> as early as 1940's. This boundary resistance is named K apitza resistance after him. Later, it is found that such a K apitza resistance exists at the interface between any pair of dissin ilarm aterials. K halatnikov<sup>34</sup> developed the acoustic m ism atch m odel to explain the K apitza resistance. Since then, continuous e orts have been devoted to this problem. M ore inform ation can be found in the review by Swartz and P ohl<sup>35</sup>.

The Kapitza resistance is de ned as

$$R = T = J;$$
 (12)

where J is the heat current and T the temperature di erence between two sides of the interface.

In our system, the temperature drops are dimensional when the temperature gradient of the system is reversed as shown in Fig. 6. Therefore, we use  $R_+$  and  $R_-$  to denote the interface resistance for the case of > 0 and < 0 momentumly

< 0, respectively.



FIG.7: (Color Online) (a) Interface therm al resistance R versus  $T_0$ .j j= 0.5. (b) The ratio R =  $R_+$  versus  $T_0$ .  $N_Y = 4$ ;  $N_X = 10$ .

In Fig7 and Fig8, we show the dependence of IRT on tem perature T<sub>0</sub> and the norm alized tem perature di erence . From the two qures we can see that, generally, (with larger tem perature drop) is about two or three R orders of m agnitude larger than R+ (with sm aller tem perature jum p). Both  $R_+$  and  $R_-$  decrease with  $T_0$  until 02, then both becom e approxim ately constants. In Τo Fig7b, we show the ratio R =  $R_+$  versus tem perature  $T_0$ . It is clearly seen that there exists an optim altern perature value for the ratio  $R = R_+$ . In Fig8, we show the resistance versus tem perature di erence. W e can see that R m onotonically increases with tem perature di erence until it reaches a maximum value, while R<sub>+</sub> monotonically decreases with increasing . If we plot the ratio of R over R+ versus tem perature di erence, we nd that the relationship between them also obeys the exponential law like the ratio of heat current.

C om paring Fig7 and Fig8 with Fig3 and Fig5, we can nd that the behaviors of the IRT and heat current through the system is very similar, both are asymmetric, both the ratio R =R<sub>+</sub> and J<sub>+</sub> =J have an optimum value under di erent temperature and obey exponential law when changing temperature di erence. The asym-



FIG.8: (ColorOnline) (a) R versus the norm alized tem perature di erence j j.T  $_0$  = 0.037. (b) The ratio R =R<sub>+</sub> versus j j.N  $_{\rm Y}$  = 8;N  $_{\rm X}$  = 20:

m etry of them al resistance when reversing tem perature gradient is the determ inant factor for the rectifying e ect on heat current of the system from the form ula (12).

# V. PHYSICAL MECHANISM OF RECTIFYING EFFECT: AN ANALYSIS OF LATTICE VIBRATION SPECTRUM

From above investigation, we know that the asym m etric interface therm al resistance determ ines the asym m etry of heat current when reversing tem perature gradient on the system, but what cause the asym m etrical behavior of the IT R? In this section, we will answer this question from a fundam ental point of view : lattice vibration spectrum. Lattice vibration is responsible to heat transport in our m odel. An e ective way to get the spectrum of lattice therm al vibration is the discrete faster Fourier transform (DFFT) for the lattice velocity<sup>36</sup>.

In our model, the vibration has two components,  $v_x$  and  $v_y$ . We can use the theorem of equipartition of energy to simplify the numerical calculation. A coording to



FIG. 9: (Color Online) DFFT of  $v_x; v_y$ . The shadowed regions represent the integral of the power spectra. 2S ( $P_x$  (!=2)=L) = 0:05 =  $hv_x^2$ i T,2S ( $P_y$  (!=2)=L) = 0:05 =  $hv_y^2$ i T.

the equipartition theorem , the m olecules in therm alequilibrium (here we have local therm al equilibrium ) have the sam e average energy associated with each independent degree of freedom of their motion and that energy is  $k_{\rm B}\,T=2$ . For our system , we have m  $hv^2\,i=2=~k_{\rm B}\,T$ , m  $hv_{\rm x}^2\,i=2=~m~hv_{\rm y}^2\,i=2=~k_{\rm B}\,T=2$ .

In our calculation, m = 1,  $k_B = 1$ . So we have  $hv_x^2 i = hv_y^2 i = T$ . If we do the DFFT of  $v_x$ and  $v_{y}$  separately, we should have,  $\lim_{i=0}^{L-1} jv_x (t) f =$  $\sum_{j=0}^{L=2} 2 P_x(j) j$  and  $\sum_{j=0}^{P} y_y(t) j = 0$ f  $P_{\substack{L=2\\ j=0}}^{j=0}$  2 $p_{y}(j)$ <sup>2</sup>. Here P (f) is the Fourier transform of velocity v(t). From the equipartition theorem, one  $P \stackrel{L}{\underset{i=0}{\overset{1}{\xrightarrow{}}}} \stackrel{1}{y}_{x} (t) \stackrel{2}{J} = L = hv_{x}^{2} i \text{ and } P \stackrel{L}{\underset{i=0}{\overset{1}{\xrightarrow{}}}} \stackrel{1}{y}_{y} (t) \stackrel{2}{J} = L = hv_{y}^{2} i$   $n \text{ above analysis, we have } f \stackrel{P \stackrel{i=0}{\underset{i=0}{\overset{1}{\xrightarrow{}}}} \stackrel{1}{y}_{x} (j) \stackrel{2}{J} = L =$ has From above analysis, we have f  $P_{j=0} \stackrel{L=2}{\xrightarrow{}} 2p_{y}(j) \stackrel{2}{\xrightarrow{}} L = T: The power spectra of$ f Τ; vibration obtained from DFFT of  $v_x$  and  $v_y$  agree with the above form ula very well (see Fig9). The integral of power spectra is exactly equal to the tem poral average of  $v_x^2$  and  $v_y^2$  individually. There is a slight di erence between  $hv_x^2 \, i$  and  $hv_v^2 \, i$  . The dierence m ight be caused by the number of sam pled data or the di erent boundary conditions in X; Y direction. In the formula, L should be in nite.

In our system, we nd that the asymmetrical IT R and heat current are strongly related with the overlap of vibration spectra of the particles at the two sides of the interface. W hen the vibration spectra overlap with each other, the system behaves like a therm alconductor, while the system behaves like a therm alionductor when the vibration spectra are separated.

P hysically, whether an excitation of a given frequency can be transported through a mechanical system depends on whether the system has a corresponding eigenfrequency. If the frequency m atches, the energy can easily go through the system, otherwise, the excitation will be re ected. In our system, the overlap of the two spectra m eans that there exists com m on vibrational frequency in two parts of the system. The excitation (here as phonon) of such com m on frequency can be transported from one part to the another. However, if the vibrational spectra of two parts are separated, then the excitation at any part cannot be transported to another part, because there exists no such corresponding frequency in another part.

The change from overlap to separation is induced by the di erent temperature dependence of the vibration spectra of the two segments, which is a general feature of any anham onic lattice.

In Fig10, we show the vibration spectra of the FK part and the FPU part under di erent tem peratures. We can see that the vibration spectra of the FK part broaden from high frequency to low frequency when increasing the system temperature. This is because at low tem – perature, the atom s of the FK model is con ned at the valley of the on-site potential, thus the atom s oscillate in very high frequency, how ever, when the temperature is increased, more and more low frequency modes can be excited. In the lim iting case, when the temperature is larger enough that the kinetic energy of the atom ism uch larger than the on-site potential, then the FK model becomes a chain of harm onic oscillators which has frequency ! 2 [0;2]  $k_{\rm FK}$ ].

On the contrary, the vibration spectra of the FPU part broaden from low frequency to high frequency. In fact, we have show  $n^{26}$  that the highest oscillation frequency of T<sup>1=4</sup>. the FPU model depends on tem perature,  $!_{FPU}$ Therefore, in some settings, the vibration spectra of the FK part and the FPU part will overlap with each other, while in other tem perature settings, they will separate with each other. These are shown in Fig11. The com parison of vibration spectra of the FK part at two di erent tem perature ranges and the FPU part at the full tem perature range from 0.01 to 0.12 are shown in Fig11a and Fig11b separately. We can see that the vibration spectra of the FK part and the FPU part are m atched with each other when the tem perature of the FK part is from 0.05 to 0.12 (see Fig11a). The vibration spectra of the two parts are separated from each other when the tem perature of the FK part is from 0.01 to 0.03 (see Fig11b). This indicates that when the tem perature of the FK part is below a certain value, which we call  $T_c$  (0:04 0:045), the system will behave like a therm al insulator since the separated vibration spectra of the interface particles m ake the heat conduction alm ost im possible. W hen the tem perature of the FK part is above the critical point T<sub>c</sub>, the system will be a good therm al conductor since the matched vibration spectra allow the heat ow. Thus, if we adjust  $T_0$  and appropriately to make  $T_{high}$  $T_c$  and Tlow  $T_c$ , the system will have a good rectifying e ect. If  $T_{\rm high}\,;T_{\rm low}~>~T_{\rm c}$  or  $T_{\rm high}\,;T_{\rm low}~<~T_{\rm c}$  , the rectifying e ect is very poor. The above analysis is based on the



FIG.10: (Color Online) V ibration spectra of the interface particles at di erent temperature. (a) The vibration spectra of the particles in the FK segment.(b) The vibration spectra of the particles in the FPU segment.

vibration spectra of the system with N<sub>Y</sub> = 8;N<sub>X</sub> = 20. It is consistent with the result obtained in Section III.

Now we look back at Fig3. The optimum point is at  $T_0$  = 0.037 for  $N_{\rm Y}$  = 8; $N_{\rm X}$  = 20, corresponding  $T_{\rm high}$  = 0.0505 >  $T_{\rm c}$  and  $T_{\rm low}$  = 0.0235 <  $T_{\rm c}$ . The electrive tem perature range  $T_{\rm e}$  with j j= 0.5 is from 0.0261 to 0.0481. The low tem peratures are all sm aller than  $T_{\rm c}$  and all high tem peratures are larger than  $T_{\rm c}$ . Both decreasing  $T_0$  and increasing  $T_0$  in the outside region of  $T_{\rm e}$  lead the system to the two extrem ecases  $T_{\rm high}$ ;  $T_{\rm low}$   $T_{\rm c}$  with poor performance. From the above analysis, we can say that the dilerent properties of heat current under dilerent tem perature and tem perature dependence of the vibration spectra of the two segments.

In term s of the vibration spectra of the particles in the interface, the complex behavior of  $jJ_j$  in F ig 4 can be explained from the vibration spectrum. In particular, in the range from  $_1$  to  $_2$ , a novel phenom enon-called the negative di erential therm al resistance phenom enon is observed in R ef.<sup>25</sup> and fully discussed in R ef.<sup>37</sup>. In this particular tem perature interval, a larger tem perature dif-



FIG.11: (ColorOnline) Comparison of the spectra of the FK part and the FPU part at di erent temperature region. (a) The spectra of the FPU part at  $T_{F\,P\,U} = 0.01 \quad 0.09$  (from bottom to top) and the FK part at  $T_{F\,K} = 0.01 \quad 0.04$ . (b) The spectra of the FPU part at  $T_{F\,P\,U} = 0.01 \quad 0.09$  and the FK part at  $T_{F\,K} = 0.01 \quad 0.09$  and the FK part at  $T_{F\,K} = 0.01 \quad 0.09$  and the FK part at  $T_{F\,K} = 0.01 \quad 0.09$ 

ference can induce a smaller heat current. The negative di erential therm al resistance can be understood from the overlap and separation of the vibration spectra of the interface particles. This phenom enon is valid for a wide range of the param eters. Moreover, in  $\text{Ref}^{27}$ , Li. et. al. show that it is this negative di erential therm al resistance property that makes the therm al transistor possible.

M ore importantly, we nd a speci c relationship between the overlap of the vibration spectra of the two segm ents and the ratio R = R\_+ in the interface or the ratio  $jJ_+=J_-j$  from two directions. We introduce the following quantity to describe overlap of the vibration spectra,

$$S = \frac{R}{P_{1}^{x}(f)P_{r}^{x}(f)df} = \frac{R}{P_{1}^{x}(f)P_{r}^{x}(f)df} = \frac{R}{T_{int}^{L}T_{int}^{R}}$$
(13)

S corresponds to the case of > 0 and < 0, respectively. In Fig12, we plot  $S_+ = S$  versus  $R = R_+$  and  $jJ_+ = J_-$  j. A very good power law was found between the ratio of resistances or heat currents and the overlap of



FIG.12: (Color Online) The bullet are the ratios of heat current  $j J_+ = J_{\phantom{1}} jversus S_+ = S_{\phantom{1}}$ . Square are the ratios of the IT R R  $= R_+$  versus  $S_+ = S_{\phantom{1}}$ . The dotted line has a slope 1:35 0:03.

the vibration spectra;  $j_{+} = J_{-} j_{-} R_{-} R_{+} / (S_{+} = S_{-})$ The best t for the ratio of current suggests the power law constant = 1:35 0:03. The two gures Fig11 and Fig12 give us a very clear and quantitative picture about the dependence of the rectifying e ect of the system on the vibration spectra.

Since the rectifying e ect sensitively depends on the overlap of the vibration spectra, we may nd answers in F ig13 for the behavior of the 2D system responding to the tem perature changes at di erent conditions. We can see clearly that when we change the num ber of particles in Y direction, the tem perature for the optim um perform ance will change, whereas when we change the num ber of particles in X direction, the tem perature for OP are kept at the same value. And the value of the tem perature for the OP at di erent conditions found by the overlap are consistent with the value in F ig3. These results suggest that the di erent vibration spectra of the two segments and the overlap between them are the determ inant factors of the system complex behaviors.

#### VI. DISCUSSION AND CONCLUSIONS

In this paper, we have studied the therm al rectifying e ect in a 2D anharm onic lattice. The perform ance of the 2D therm al recti er under di erent environm ent changes, such as system temperature and the temperature di erence on the two sides of the system, have been investigated system atically. We nd that there exits an optimum perform ance (OP) for a speci c therm al recti er at certain temperature range. The OP is a ected by the boundary condition and the number of particles,  $N_Y$ , along Y direction. The OP shifts to lower tem – perature when increasing  $N_Y$  or changing the periodic boundary condition to the free boundary condition along



FIG.13: (ColorOnline) The ratio of the overlap of vibration spectra  $S_{+}=S_{-}$  versus  $T_{0}$  at di erent conditions. (a) Com parison at three di erent N<sub>Y</sub> with N<sub>X</sub> = 20.(b) Com parison at three di erent N<sub>X</sub> with N<sub>Y</sub> = 8.

Y direction. The 2D therm alrecti er has a good rectifying e ciency in a very wide tem perature range. A nother im portant factor that a ects the perform ance of the therm al recti er is the tem perature di erence between the two ends. W e nd the rectifying e ciency increases approxim ately as an exponential law in certain tem perature range with the tem perature di erence. The rectifying efciency is mainly determ ined by the asym metrical ITR. The study on the ITR shows the sim ilar behavior with heat current.

The behaviors of the ITR and heat current of the system are strongly correlated with vibration spectra of the particles beside the interface. The asymmetry behavior of ITR and heat current is induced by the di erent tem perature dependence of the vibration spectra of the two parts beside the interface. We nd the vibration spectra of the FK part broaden from high frequency to low frequency, conversely, the vibration spectra of the FPU part broaden from low frequency to high frequency as the tem perature increases. The di erent tem perature dependence of vibration spectra makes the system transition from a therm al conductor to an insulator possible by setting the system tem perature and tem perature di erence properly. Moreover a speci c relationship between the perform ance of the system and the convolution of the vibration spectra of the two parts is found num erically as power law.

O ur study on 2D therm alrecti ergives a very clearpicture about how the system responds to the environment changes. The results should be useful for further experimental investigation. The therm all diode constructed by a monolayer thin lm or a tube like structure might have many practical applications.

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